TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC164FN

8-Bit Shift Register (S-IN, P-OUT)

The TC74VHC164 is an advanced high speed CMOS 8-BIT SERIAL-IN PARALLEL-OUT SHIFT REGISTER fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of a serial-in, parallel-out 8-bit shift register with a CLOCK input and an overriding $\overline{\text{CLEAR}}$ input.

Two serial data inputs (A, B) are provided so that one may be used as a data enable.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input yoltages.

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74VHC164FN

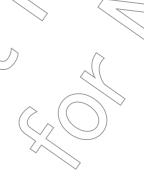
SOL14-P-150-1,27

Weight

SOL14-P-150-1.27 //: 0.12 g (typ.)

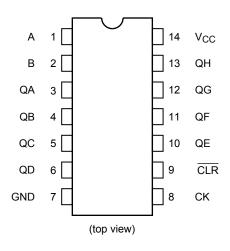
Features

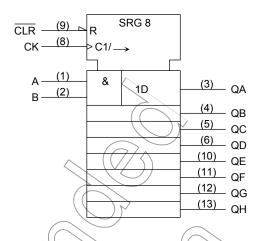
- High speed: $f_{max} = 175 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- High noise immunity: V_{NIH} = V_{NIL} = 28% (V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: tpLH \(\neq\) tpHL\(\lambda\)
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS164



Pin Assignment

IEC Logic Symbol



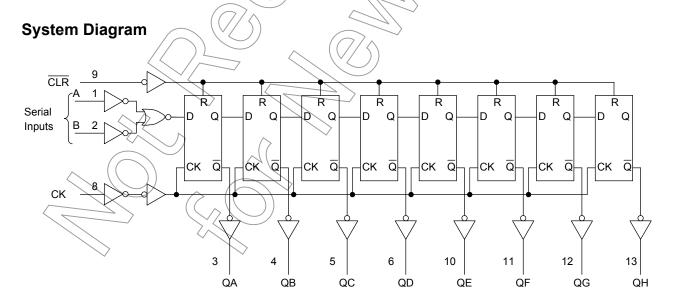


Truth Table

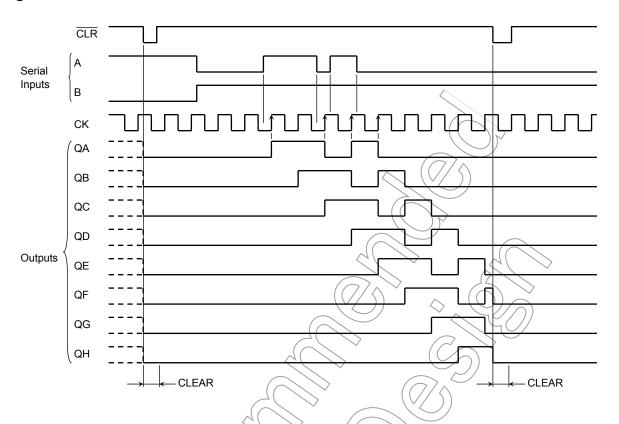
	Inp	uts			Out	puts			
CLR	СК	Seria	al IN	QA	QB		QH		
OLK	5	Α	В		טט		QII (
L	Х	Х	Х	L	L		<u> </u>		
Н	$ \rightarrow $	Х	Х	No Change					
Н	Ļ	L	Х	L	QAn	::	QGn		
Н	Ļ	X	L	L	QAn		QGn		
Н	\downarrow	Н	Н	Н	QA _n	((QGn		

X: Don't care

 QA_n to QG_n : The level of QA to QG, respectively, before the most recent positive edge of the clock.



Timing Chart



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	((V _{CC}	-0,5 to 7.0	V
DC input voltage	VIN	₹0.5 to 7.0	V
DC output voltage	У́фит	-0.5 to V _{CC} + 0.5	V
Input diode current) _{IIK}	-20	mA
Output diode current	⊃ lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	ွင့
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V
input rise and rail time	didv	0 to 20 (V _{CC} = 5 ± 0.5 V)	\ \

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol		Test Condition		()) 1	Га = 25°C			/= \85°C	Unit
Characteristics	Зупівої			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Min	Тур.	Max	Min	Max	
High-level input voltage	V _{IH}		-	2.0 3.0 to 5.5	1.50 V _{CC} × 0.7			1.50 V _{CC} × 0.7	1 1	٧
Low-level input voltage	V_{IL}			2.0 3.0 to 5.5	-) -	0.50 V _{CC} × 0.3		0.50 V _{CC} × 0.3	V
High-level output voltage	Voн	= AIH or	I _{OH} = -50 μA I _{OH} = -4 mA I _{OH} = -8 mA	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 —		1.9 2.9 4.4 2.48 3.80		٧
Low-level output voltage	Vol	= V _{IH} or V _{IL}	I _{OL} = 50 μA I _{OL} = 4 mA I _{OL} = 8 mA	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 —	0.1 0.1 0.1 0.36 0.36		0.1 0.1 0.1 0.44 0.44	٧
Input leakage current)) I _{IN}	V _{IN} = 5.5	V or GND	0 to 5.5	_	_	±0.1		±1.0	μΑ
Quiescent supply current	Ica	VIN = VC	or GND	5.5	_		4.0	_	40.0	μΑ



Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40 to 85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t _{w (L)}		3.3 ± 0.3	_	5.0	5.0	20
(CK)	t _{w (H)}	_	5.0 ± 0.5 <	_	5.0	5.0	ns
Minimum pulse width	4		3.3 ± 0.3)	5.0	5.0	20
(CLR)	t _{w (L)}	_	5.0 ± 0.5	((-)	5.0	5.0	ns
Minimum out un timo			3.3 ± 0.3		5.0	6.0	20
Minimum set-up time	t _s	_ <	5.0 ± 0.5	$\langle \cdot \rangle$	4.5	4.5	ns
Minimum hold time	4.		3.3 ± 0.3		0.0	0.0	20
Minimum noid time	t _h	_	5.0 ± 0.5	· —	1.0	1.0	ns
Minimum removal time			3.3 ± 0.3	_	2.5	2.5	20
(CLR)	t _{rem}		5.0 ± 0.5	-	2.5	2,5	ns

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

				\ \ \ /		<>		<u> </u>	1	
Characteristics	Symbol	Tes	est Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	- J		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	[→] Min	Max	
			3.3 ± 0.3	15		8.4	12.8	1.0	15.0	
Propagation delay time	t _{pLH}	_	3.3	50	-	10,9 <	16.3	1.0	18.5	ns
(CK-Q)	t _{pHL}	_	5.0 ± 0.5	15	$\left(1 \right)$	5.8	9.0	1.0	10.5	113
			3.0 1 0.3	50//	_	7.3	11.0	1.0	12.5	
	t _{pHL}		3.3 ± 0.3	15		8.3	12.8	1.0	15.0	
Propagation delay time			9.0 1 0.0	50		10.8	16.3	1.0	18.5	ns
(CLR -Q)			5.0 ± 0.5	15	_	5.2	8.6	1.0	10.0	110
				50	> -	6.7	10.6	1.0	12.0	
	f _{max} –		3.3 ± 0.3	15	80	125	_	65	_	
Maximum clock					50	75	_	45	_	MHz
frequency			5.0 ± 0.5	<u>)</u> 15	125	175	_	105	_	
			0.0 20.0	50	85	115	_	75	_	
Input capacitance	CIN				_	4	10	_	10	pF
Power dissipation capacitance	СРО	\wedge		(Note)	1	76	-	_	ı	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

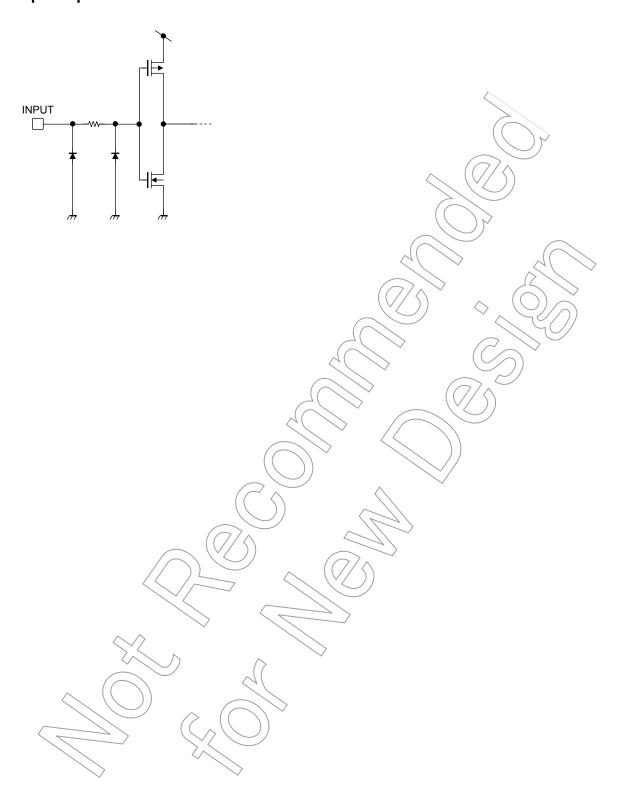
Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·TIN + ICC

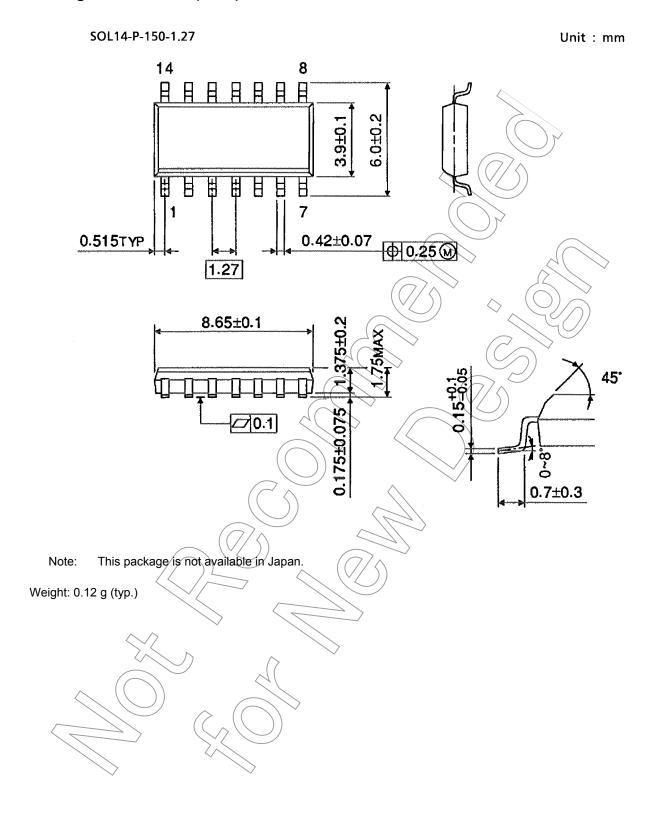
Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta =	Unit		
Characteristics	Syllibol		V _{CC} (V)	Тур.	Max	Offic
Quiet output maximum dynamic V _{OL}	V_{OLP}	C _L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

Input Equivalent Circuit



Package Dimensions (Note)



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